**TOSHIBA Photocoupler Photorelay** 

# **TLP224G,TLP224G-2**

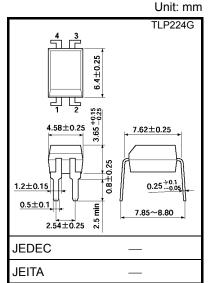
Modems PBX

**Telecommunications** 

The TOSHIBA TLP224G series consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a 4 pin DIP (DIP4), which is suitable for equipment for high tech communications, including modems.

The TLP224G series complies with FCC part  $68\ \mathrm{rules}$  with current limiting function.

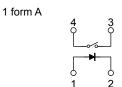
- TLP224G: 4 pin DIP, 1 channel type (1 form A)
- TLP224G-2: 8 pin DIP, 2 channel type (2 form A)
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- Load current limiting: 150 mA to 300 mA (t = 5 ms)
- On-state resistance: 35 Ω (max)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1577, file No. E67349

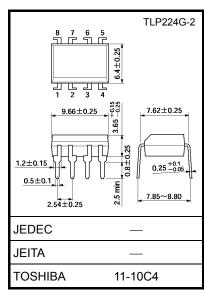


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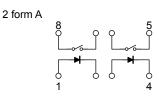
Weight: 0.26 g (typ.)

**TOSHIBA** 

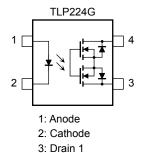




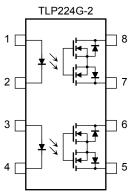
Weight: 0.54 g (typ.)



## Pin Configuration (top view)



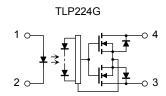
4: Drain 2



- 1, 3: Anode
- 2, 4: Cathode
- 5: Drain 1
- 6: Drain 2
- 7: Drain 3
- 8: Drain 4

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#### **Internal Circuit**



#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristics	Symbol	Rating	Unit
LED	Forward current	lF	50	mA
	Forward current derating (Ta ≥ 25°C)	ΔI <sub>F</sub> /°C	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I <sub>FP</sub>	1	А
	Reverse voltage	$V_{R}$	6	V
	Junction temperature	Tj	125	°C
	Off-state output terminal voltage	V <sub>OFF</sub>	350	V
	On-state current (Note 1)	I <sub>ON</sub>	120	mA
Detector		Δl <sub>ON</sub> /°C	-1.2	mA/°C
	Junction temperature	Tj	125	°C
Storage ter	mperature range	T <sub>stg</sub>	-55 to 125	°C
Operating	temperature range	T <sub>opr</sub>	-40 to 85	°C
Lead solde	ering temperature (10 s)	T <sub>sol</sub>	260	°C
Isolation vo	oltage (AC, 1 min., R.H. ≤ 60%) (Note 2)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Two channels operating simultaneously.

Note 2: Device considered a two-terminal device: LED side pins shorted together, and detector side pins shored together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	$V_{DD}$	_	_	280	V
Forward current	lF	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	100	mA
Operating temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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## Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 6 V	_	_	10	μА
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 350 V	_	_	1	μА
	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	40	_	pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	_	1	3	mA
Load current limiting	I <sub>LIM</sub>	$I_F = 5 \text{ mA}, V_{DD} = 5 \text{ V}, t = 5 \text{ ms}$	150	_	300	mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA	_	22	35	Ω

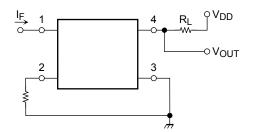
## Isolation Characteristics (Ta = 25°C)

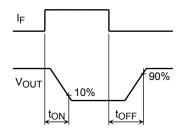
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1 MHz	_	8.0	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage		AC, 1 minute	2500	_	_	Vrms
	$BV_S$	AC, 1 second (in oil) 50	5000	_	VIIIIS	
		DC, 1 minute (in oil)	_	5000	_	Vdc

## **Switching Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	ton	$ \begin{array}{l} \text{R}_{L} = 200 \; \Omega \\ \text{V}_{CC} = 20 \; \text{V}, \; \text{I}_{F} = 5 \; \text{mA} \end{array} $ (Note)	_	_	1	ms
Turn-off time	t <sub>OFF</sub>	$\label{eq:RL} \begin{array}{l} \text{R}_{L} = 200~\Omega \\ \text{V}_{CC} = 20~\text{V},~\text{I}_{F} = 5~\text{mA} \end{array} \tag{Note}$	_	_	1	ms

Note: Switching time test circuit





#### **RESTRICTIONS ON PRODUCT USE**

Handbook" etc.

20070701-EN

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